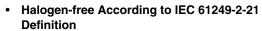


P-Channel 60 V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}(\Omega)$	V _{GS(th)} (V)	I _D (mA)		
- 60	2.8 at V _{GS} = - 10V	- 1 to - 3	-500		

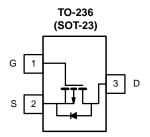
FEATURES

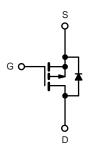




RoHS

- TrenchFET® Power MOSFET
- High-Side Switching
- Low On-Resistance: 2.8 Ω
- Low Threshold: 2 V (typ.)
- Fast Swtiching Speed: 20 ns (typ.)
- Low Input Capacitance: 20 pF (typ.)
- Compliant to RoHS Directive 2002/95/EC





P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted					
Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V _{DS}	- 60	V	
Gate-Source Voltage		V _{GS}	± 20	V	
Continuous Drain Current ^a	T _A = 25 °C	. I _D	- 500		
Continuous Drain Current	T _A = 100 °C		- 380	mA	
Pulsed Drain Current ^b		I _{DM}	-1500		
Davias Diagination	T _A = 25 °C	- P _D	460	mW	
Power Dissipation ^a	T _A = 100 °C		240		
Maximum Junction-to-Ambient ^a		R _{thJA}	350	°C/W	
Operating Junction and Storage Temperature Range		T _{J,} T _{stg}	- 55 to 150	°C	

Notes

- a. Surface mounted on FR4 board.
- b. Pulse width limited by maximum junction temperature.

服务热线:400-655-8788

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SPECIFICATIONS T _A = 25°	C, unless oth	erwise noted	1				
			Limits		1		
Parameter	Symbol	Test Conditions	Min.	Typ. ^a	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_{D} = -10 \mu\text{A}$	- 60			V	
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	- 1		- 3	V	
		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$	± 10		± 10	μΑ	
Gate-Body Leakage		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 10 \text{ V}$			± 200	nA	
Gale-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 10 \text{ V}, T_{J} = 85 ^{\circ}\text{C}$			± 500		
		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 5 \text{ V}$			± 100		
Zero Gate Voltage Drain Current		V _{DS} = - 60 V, V _{GS} = 0 V			- 25		
	I _{DSS}	V _{DS} = - 60 V, V _{GS} = 0 V, T _J = 85 °C			- 250		
On-State Drain Current ^a	,	V _{GS} = - 10 V, V _{DS} = - 4.5 V	- 4.5 V - 50			A	
	I _{D(on)}	V _{GS} = - 10 V, V _{DS} = - 10 V	- 600			- mA	
		V _{GS} = - 4.5 V, I _D = - 25 mA		3		Ω	
Drain-Source On-Resistance ^a	R _{DS(on)}	V _{GS} = - 10 V, I _D = - 100 mA		2.8			
		V _{GS} = - 10 V, I _D = - 100 mA, T _J =125 °C		9			
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 10 V, I _D = - 100 mA	80			mS	
Diode Forward Voltage	V _{SD}	I _S = - 100 mA, V _{GS} = 0 V			- 1.4	V	
Dynamic	·						
Total Gate Charge	Qg			2.0		nC	
Gate-Source Charge	Q _{gs}	$V_{DS} = -30 \text{ V}, V_{GS} = -15 \text{ V}$ $I_{D} \cong -100 \text{ mA}$		1.2			
Gate-Drain Charge	Q _{gd})		0.8			
Input Capacitance	C _{iss}			23		pF	
Output Capacitance	C _{oss}	$V_{DS} = -25 \text{ V}, V_{GS} = 0 \text{ V}$ f = 1 MHz		10			
Reverse Transfer Capacitance	C _{rss}	1 - 1 1 1 1 2		5			
Switching ^b	•		•				
Turn-On Time	t _{d(on)}	$V_{DD} = -25 \text{ V}, R_{L} = 150 \Omega$		20			
Turn-Off Time	t _{d(off)}	$I_D \cong$ - 200 mA, $V_{GEN} =$ - 10 V, $R_g =$ 10 Ω		35		ns	

Notes:

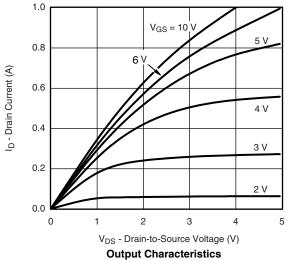
- a. Pulse test: PW $\leq 300~\mu s$ duty cycle $\leq 2~\%.$
- b. Switching time is essentially independent of operating temperature.

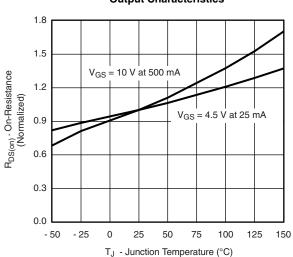
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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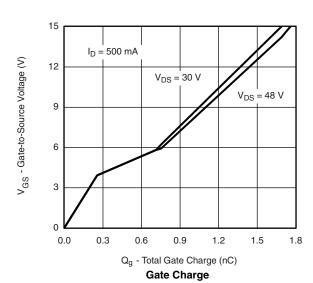


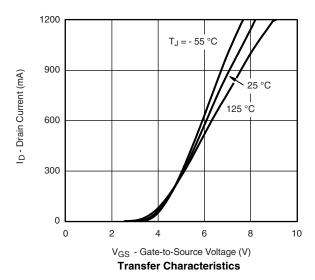
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

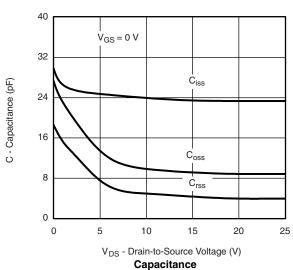




On-Resistance vs. Junction Temperature



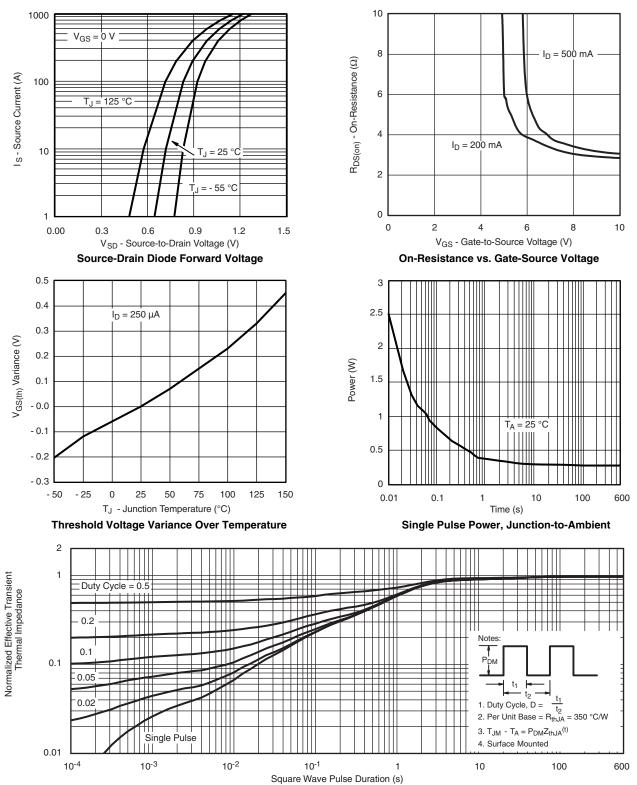




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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

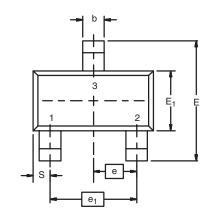


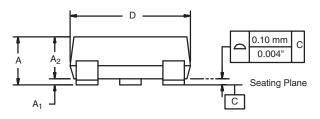
服务热线:400-655-8788

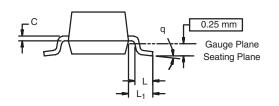
Normalized Thermal Transient Impedance, Junction-to-Ambient



SOT-23 (TO-236): 3-LEAD







Dim	MILLIMETERS		INCHES		
	Min	Max	Min	Max	
Α	0.89	1.12	0.035	0.044	
A ₁	0.01	0.10	0.0004	0.004	
A ₂	0.88	1.02	0.0346	0.040	
b	0.35	0.50	0.014	0.020	
С	0.085	0.18	0.003	0.007	
D	2.80	3.04	0.110	0.120	
E	2.10	2.64	0.083	0.104	
E ₁	1.20	1.40	0.047	0.055	
е	0.95	BSC	0.0374 Ref		
e ₁	1.90	1.90 BSC		0.0748 Ref	
L	0.40	0.60	0.016	0.024	
L ₁	0.64 Ref		0.025 Ref		
S	0.50 Ref		0.020 Ref		
q	3°	8°	3°	8°	
ECN: S-03946-Rev. K. 09-	Jul-01	•			

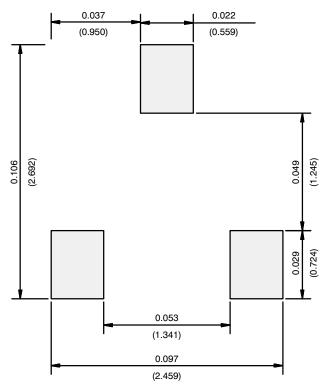
DWG: 5479

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RECOMMENDED MINIMUM PADS FOR SOT-23



Recommended Minimum Pads Dimensions in Inches/(mm)

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